

## SWITCHING N-CHANNEL POWER MOS FET

### DESCRIPTION

The μ PA1744TP is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter.

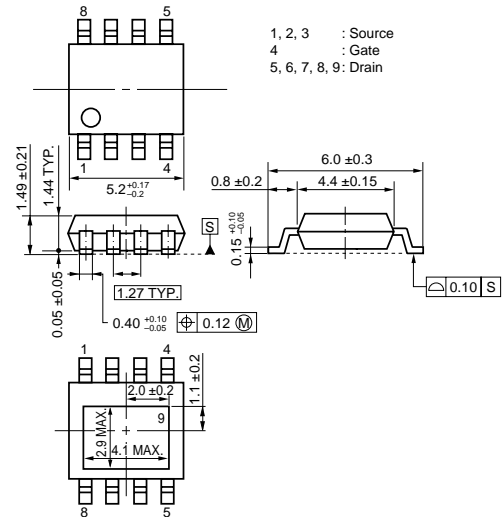
### FEATURES

- Low on-state resistance  
 $R_{DS(on)} = 30 \text{ m}\Omega \text{ MAX.}$  ( $V_{GS} = 10 \text{ V}$ ,  $I_D = 5.0 \text{ A}$ )
- Low input capacitance  
 $C_{iss} = 3400 \text{ pF TYP.}$  ( $V_{DS} = 10 \text{ V}$ ,  $V_{GS} = 0 \text{ V}$ )
- Built-in gate protection diode
- Small and surface mount package (Power HSOP8)

### ORDERING INFORMATION

PART NUMBER	PACKAGE
μ PA1744TP	Power HSOP8

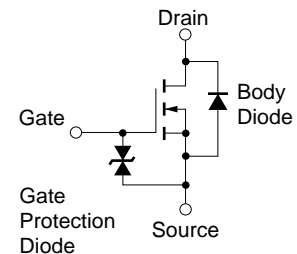
### PACKAGE DRAWING (Unit: mm)



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ , Unless otherwise noted, all terminals are connected.)

Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )	$V_{DSS}$	100	V
Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )	$V_{GSS}$	±20	V
Drain Current (DC) ( $T_C = 25^\circ\text{C}$ )	$I_{D(DC)}$	±10	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	±30	A
Total Power Dissipation ( $T_C = 25^\circ\text{C}$ )	$P_{T1}$	39	W
Total Power Dissipation ( $T_A = 25^\circ\text{C}$ ) <sup>Note2</sup>	$P_{T2}$	3.0	W
Channel Temperature	$T_{ch}$	150	°C
Storage Temperature	$T_{stg}$	-55 to +150	°C
Single Avalanche Current <sup>Note3</sup>	$I_{AS}$	10	A
Single Avalanche Energy <sup>Note3</sup>	$E_{AS}$	10	mJ

### EQUIVALENT CIRCUIT



**Notes 1.**  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

**2.** Mounted on glass epoxy board of 1 inch x 1 inch x 0.8 mm

**3.** Starting  $T_{ch} = 25^\circ\text{C}$ ,  $V_{DD} = 50 \text{ V}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0 \text{ V}$ ,  $L = 100 \mu\text{H}$

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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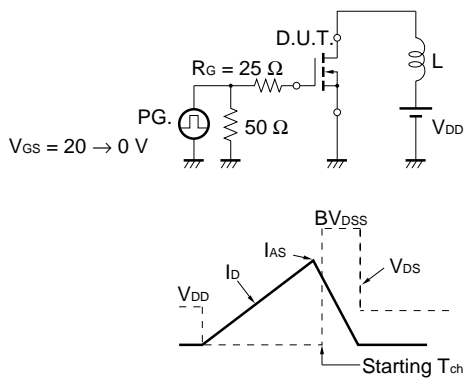
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**ELECTRICAL CHARACTERISTICS (TA = 25°C, Unless otherwise noted, all terminals are connected.)**

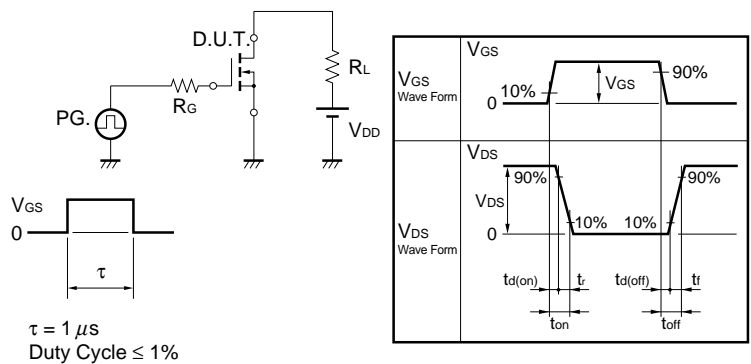
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$			10	$\mu\text{A}$
Gate Leakage Current	$I_{GSS}$	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$			$\pm 10$	$\mu\text{A}$
Gate Cut-off Voltage	$V_{GS(off)}$	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	2.5	3.0	3.5	V
Forward Transfer Admittance <sup>Note</sup>	$ y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 5.0\text{ A}$	7	14		S
Drain to Source On-state Resistance <sup>Note</sup>	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 5.0\text{ A}$		23	30	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = 10\text{ V}$		3400		pF
Output Capacitance	$C_{oss}$	$V_{GS} = 0\text{ V}$		390		pF
Reverse Transfer Capacitance	$C_{rss}$	$f = 1\text{ MHz}$		200		pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 50\text{ V}, I_D = 5.0\text{ A}$		22		ns
Rise Time	$t_r$	$V_{GS} = 10\text{ V}$		10		ns
Turn-off Delay Time	$t_{d(off)}$	$R_G = 10\ \Omega$		55		ns
Fall Time	$t_f$			7		ns
Total Gate Charge	$Q_G$	$V_{DD} = 80\text{ V}$		66		nC
Gate to Source Charge	$Q_{GS}$	$V_{GS} = 10\text{ V}$		12		nC
Gate to Drain Charge	$Q_{GD}$	$I_D = 10\text{ A}$		22		nC
Body Diode Forward Voltage <sup>Note</sup>	$V_{F(S-D)}$	$I_F = 10\text{ A}, V_{GS} = 0\text{ V}$		0.8		V
Reverse Recovery Time	$t_{rr}$	$I_F = 10\text{ A}, V_{GS} = 0\text{ V}$		65		ns
Reverse Recovery Charge	$Q_{rr}$	$di/dt = 100\text{ A}/\mu\text{s}$		170		nC

**Note** Pulsed:  $PW \leq 350\ \mu\text{s}$ , Duty Cycle  $\leq 2\%$

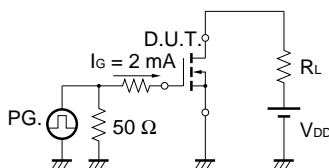
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



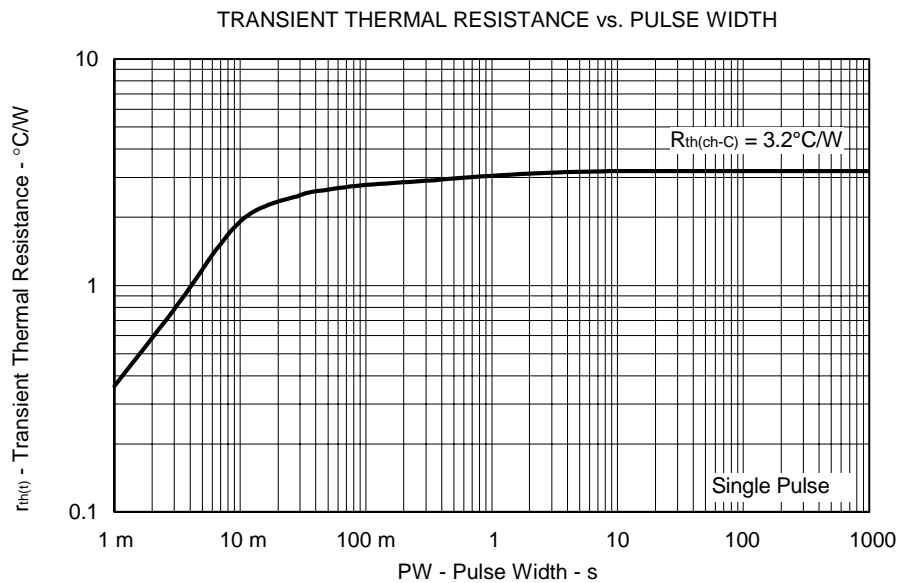
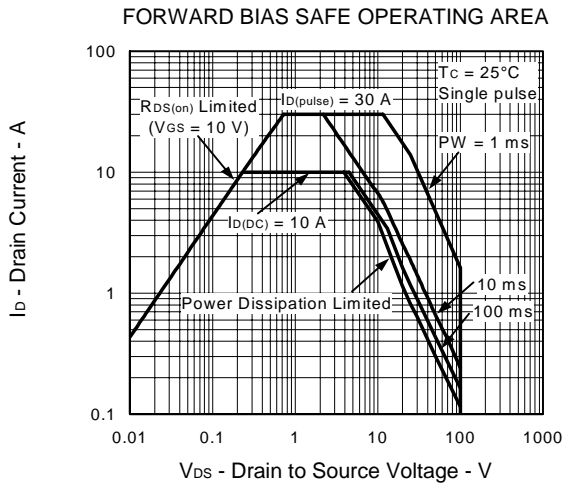
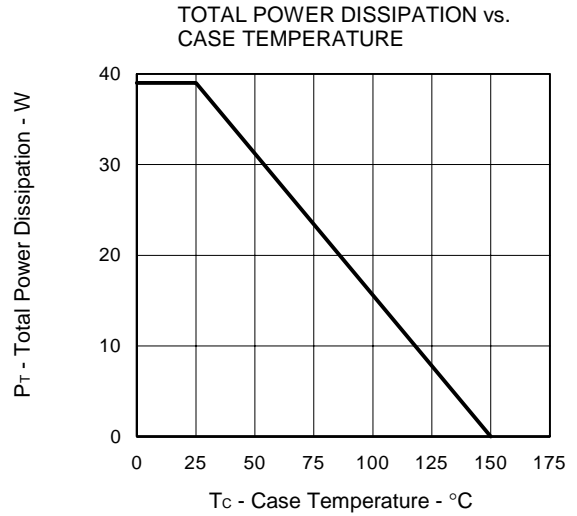
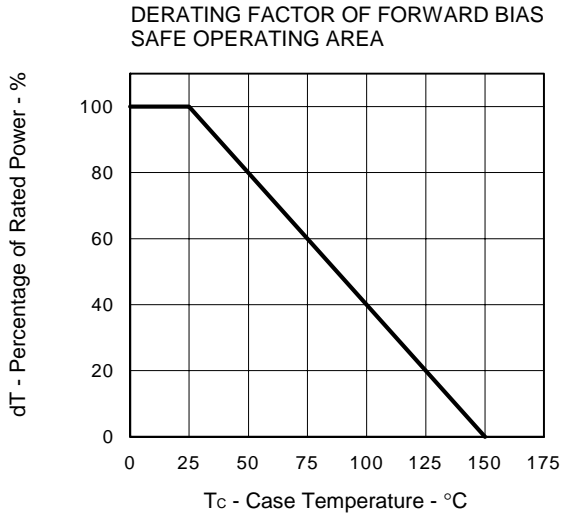
**TEST CIRCUIT 2 SWITCHING TIME**



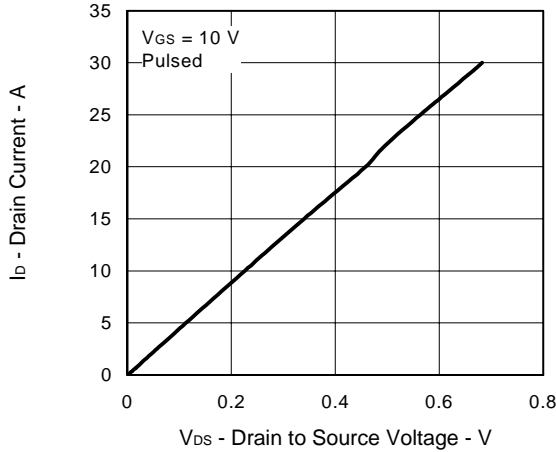
**TEST CIRCUIT 3 GATE CHARGE**



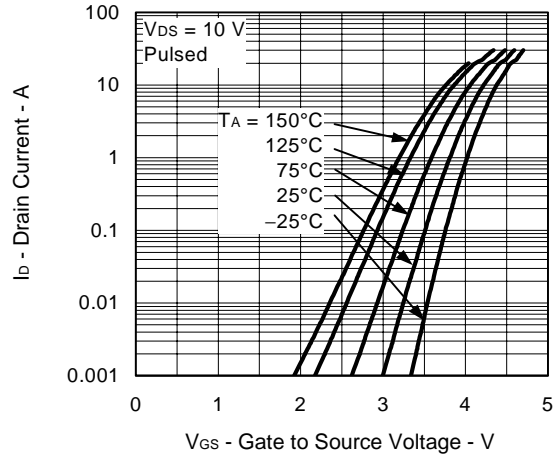
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, Unless otherwise noted, all terminals are connected.)



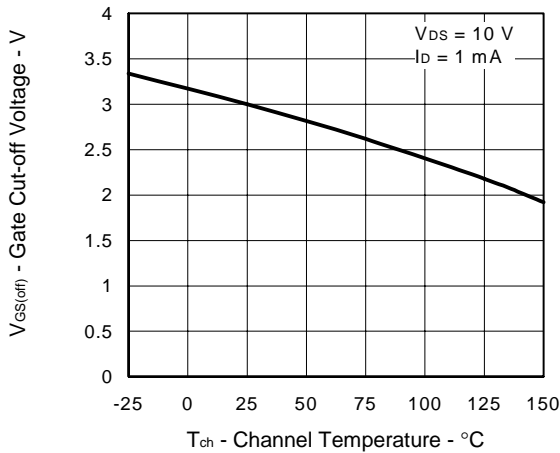
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



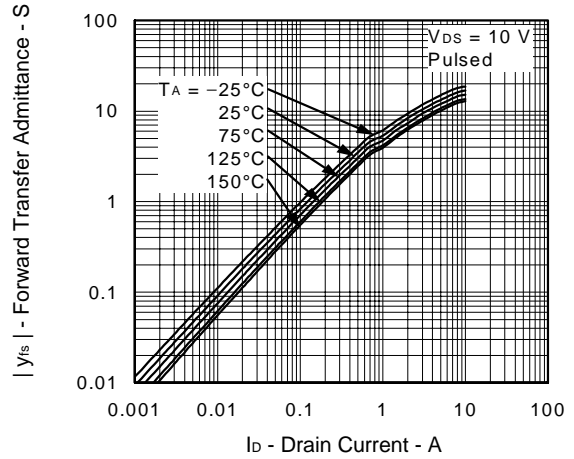
FORWARD TRANSFER CHARACTERISTICS



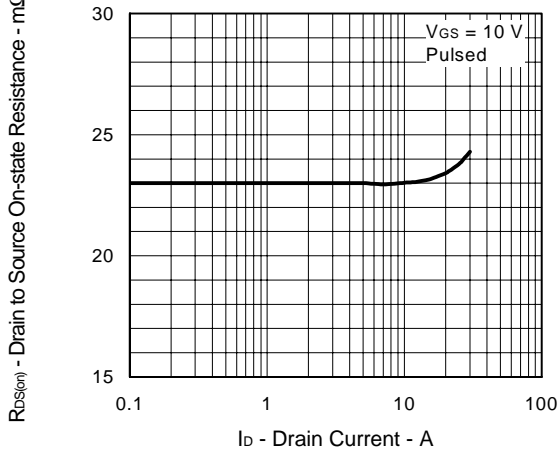
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



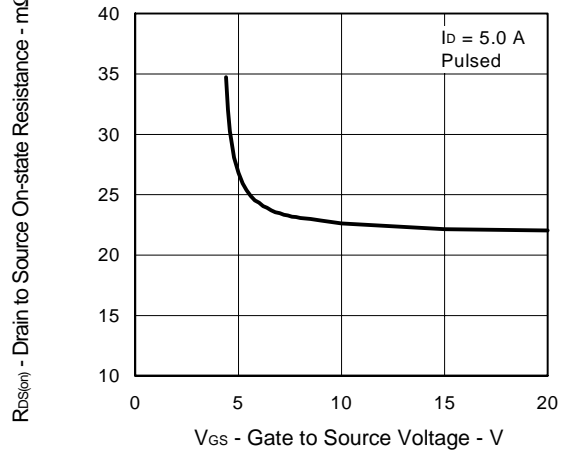
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



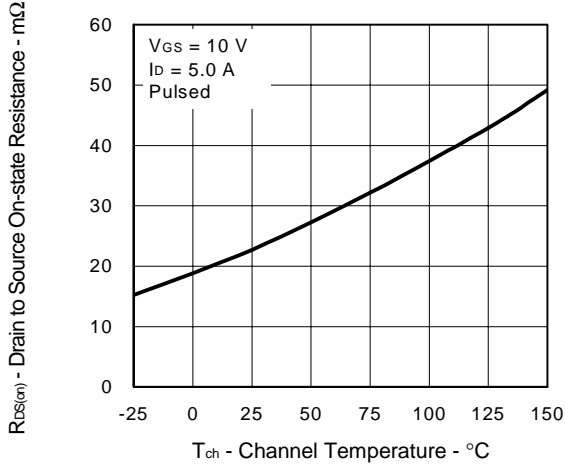
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



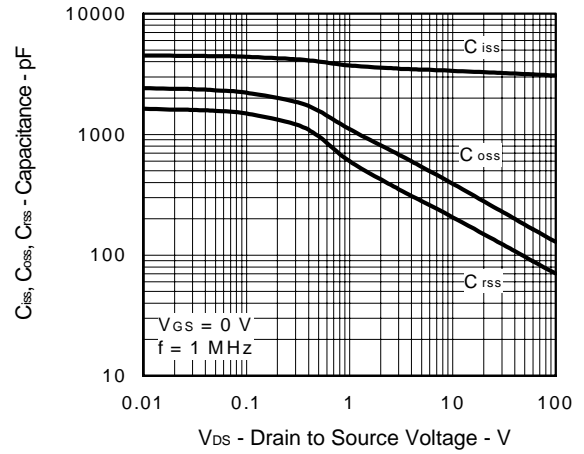
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



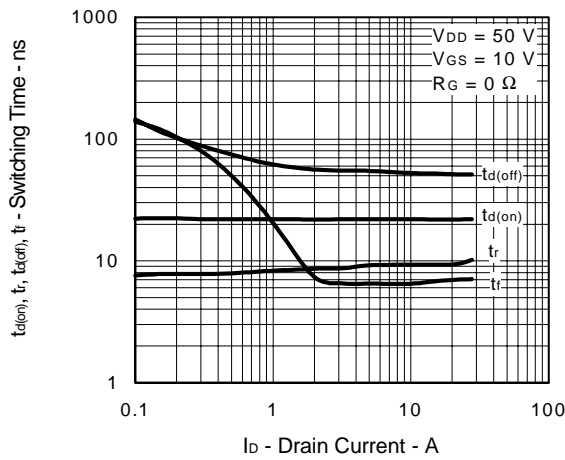
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



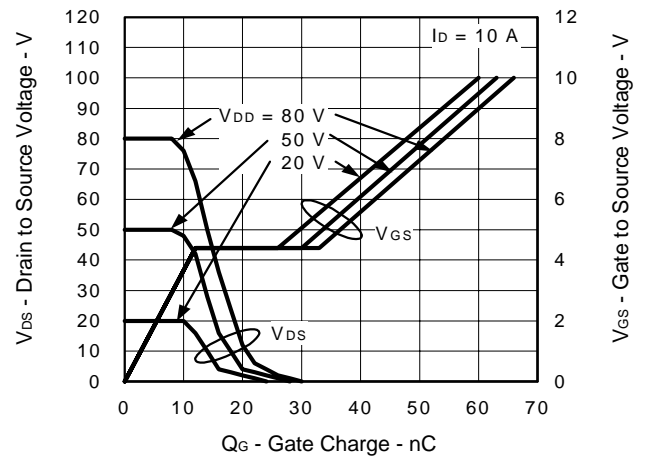
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



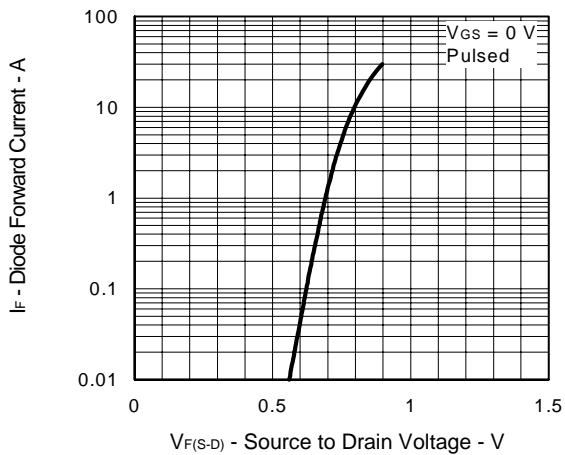
SWITCHING CHARACTERISTICS



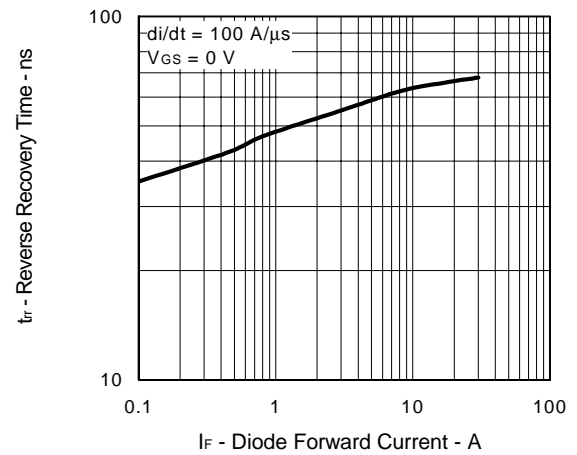
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



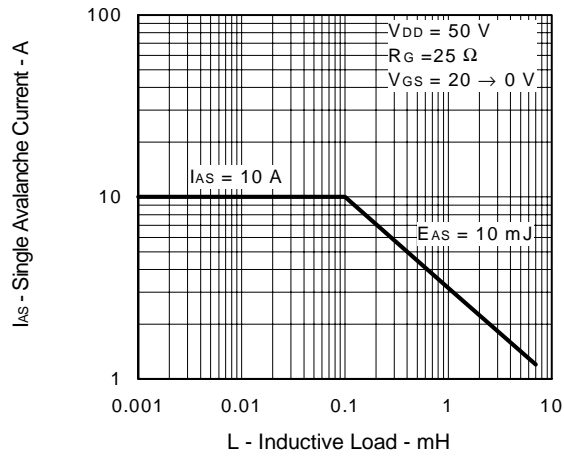
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



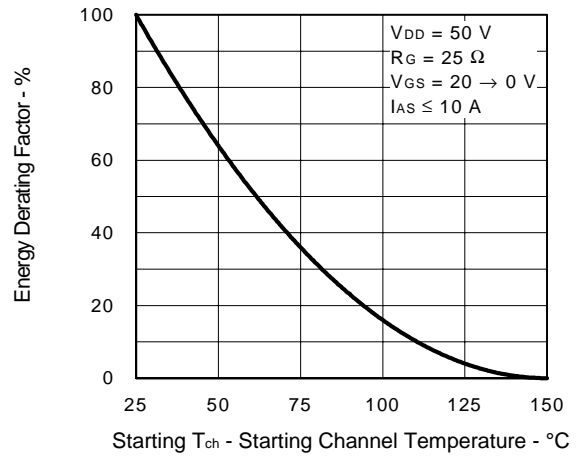
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY DERATING FACTOR



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